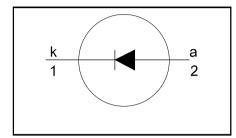
## BY359X-1500, BY359X-1500S

#### **FEATURES**

- Low forward volt drop
- · Fast switching
- Soft recovery characteristic
- High thermal cycling performance
- Isolated mounting tab

#### **SYMBOL**



#### **QUICK REFERENCE DATA**

 $V_R = 1500 \text{ V}$   $V_F \le 1.8 \text{ V} / 2 \text{ V}$   $I_{F(RMS)} = 15.7 \text{ A}$   $I_{FSM} \le 60 \text{ A}$   $t_{rr} \le 600 \text{ ns} / 350 \text{ ns}$ 

### **GENERAL DESCRIPTION**

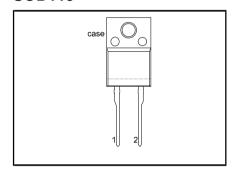
Glass-passivated double diffused rectifier diode in a plastic envelope featuring low forward voltage drop, fast reverse recovery and soft recovery characteristic. The device is intended for use in TV receivers and PC monitors.

The BY359X series is supplied in the conventional leaded SOD113 package.

#### **PINNING**

PIN	DESCRIPTION		
1	cathode		
2	anode		
tab	isolated		

### **SOD113**



#### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS		MIN.	MAX.	UNIT
V <sub>RSM</sub>	Peak non-repetitive reverse voltage			-	1500	٧
$V_{RRM}$	Peak repetitive reverse voltage			_	1500	v
V <sub>RWM</sub>	Crest working reverse voltage			-	1300	V
I <sub>F(peak)</sub>	Peak forward current	16-32kHz TV	BY359X-1500	-	10	A
, ,		31-70kHz monitor	BY359X-1500S	-	7	A
I <sub>F(RMS)</sub>	RMS forward current			-	15.7	A
FRM	Peak repetitive forward current	sinusoidal; a = 1.57		-	60	A
I <sub>FSM</sub>	Peak non-repetitive forward	t = 10 ms		-	60	A
	current	t = 8.3 ms		-	66	A
		sinusoidal; $T_j = 150 ^{\circ}C$	prior to surge;			
		with reapplied V <sub>RWM(max)</sub>				
T <sub>stg</sub>	Storage temperature	` ′		-40	150	C C
$T_j$	Operating junction temperature			-	150	°C

#### **ISOLATION LIMITING VALUE & CHARACTERISTIC**

T<sub>hs</sub> = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>isol</sub>	R.M.S. isolation voltage from both terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65% ; clean and dustfree	ı		2500	>
C <sub>isol</sub>	Capacitance from both terminals to external heatsink	f = 1 MHz	-	10	_	pF

BY359X-1500, BY359X-1500S

### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-hs</sub>	Thermal resistance junction to heatsink Thermal resistance junction to ambient	with heatsink compound without heatsink compound in free air.	1 1 1	- - 55	4.8 5.9 -	K/W K/W K/W

### STATIC CHARACTERISTICS

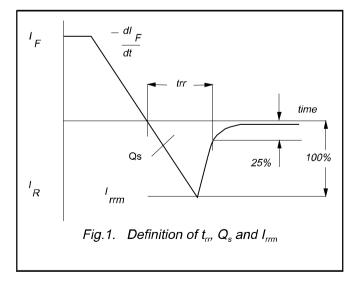
T<sub>i</sub> = 25 °C unless otherwise stated

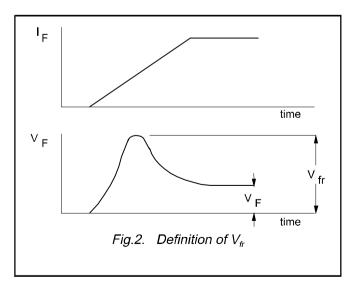
			BY359X-1500		BY359X-1500S		
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage	$I_F = 20 \text{ A}$ $I_F = 10 \text{ A}$ ; $T_i = 150^{\circ}\text{C}$	1.3 1.00	1.8 1.5	1.5 1.25	2.0 1.75	<b>&gt;</b>
<b>I</b> <sub>R</sub>	Reverse current	$\dot{V}_{R} = 1300 \text{ V}$ $V_{R} = 1300 \text{ V}$ $T_{i} = 100 ^{\circ}\text{C}$	10 50	100 300	10 100	100 600	μA μA

## **DYNAMIC CHARACTERISTICS**

T<sub>i</sub> = 25 °C unless otherwise stated

		BY359X-1500		BY359X-1500S			
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	TYP.	MAX.	UNIT
t <sub>rr</sub> Q <sub>s</sub>	Reverse recovery time Reverse recovery charge	$I_F = 2 \text{ A; } V_R \ge 30 \text{ V;} \\ -dI_F/dt = 20 \text{ A/}\mu\text{s}$	0.47 1.6	0.60 2.0	0.28 0.70	0.35 0.95	μs μC
$V_{fr}$	Peak forward recovery voltage	I <sub>F</sub> = 10 A; dI <sub>F</sub> /dt = 30 A/μs	11.0	_	17.0	-	٧





# BY359X-1500, BY359X-1500S

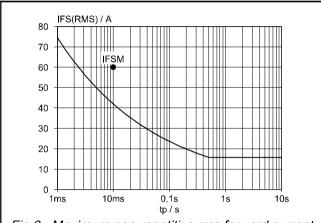


Fig.3. Maximum non-repetitive rms forward current.  $I_F = f(t_p)$ ; sinusoidal current waveform;  $T_j = 150^{\circ}C$  prior to surge with reapplied  $V_{RWM}$ .

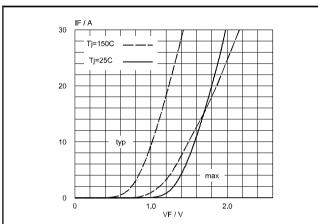


Fig.5. BY359X-1500 forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$ 

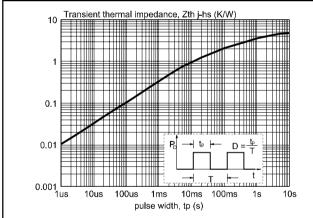


Fig.4. Transient thermal impedance  $Z_{th} = f(t_p)$ 

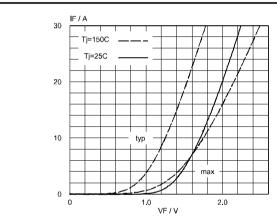
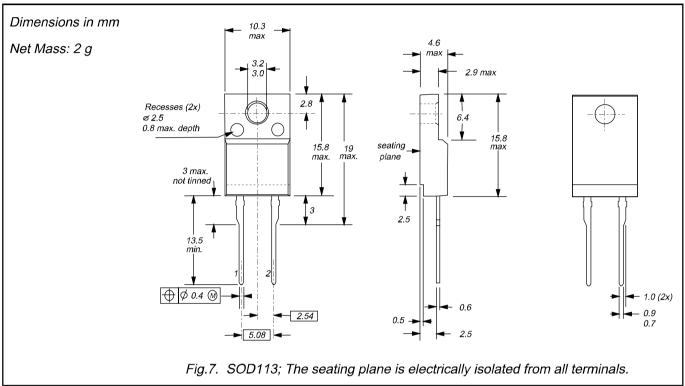


Fig.6. BY359X-1500S forward characteristic  $I_F = f(V_F)$ ; parameter  $T_i$ 

BY359X-1500, BY359X-1500S

### **MECHANICAL DATA**



### **Notes**

- Refer to mounting instructions for F-pack envelopes.
   Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

# Damper diode fast, high-voltage

BY359X-1500, BY359X-1500S

#### **DEFINITIONS**

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

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